

### 80V PNP MEDIUM POWER TRANSISTOR IN SOT223

## **Description**

This Bipolar Junction Transistor (BJT) has been designed to meet the stringent requirements of automotive applications.

### **Features**

- BV<sub>CEO</sub> > -80V
- I<sub>C</sub> = -1A High Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V<sub>CE(sat)</sub> < -500mV @ -0.5A</li>
- Complementary NPN type: BCP5616Q
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BCP5316Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Applications**

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

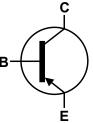
### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight: 0.112 grams (approximate)

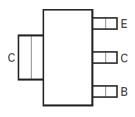




Top View



Device Symbol



Top View Pin-Out

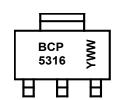
## Ordering Information (Note 4)

Ī	Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	BCP5316QTA	Automotive	BCP 5316	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



BCP = Product Type Marking Code, Line 1 5316 = Product Type Marking Code, Line 2 YWW = Date Code Marking Y = Last Digit of the Year (ex: 1 = 2021) WW = Week Code 01-52



# Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-100	V
Collector-Emitter Voltage	$V_{CEO}$	-80	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Continuous Collector Current	Ic	-1	A
Peak Pulse Collector Current	I <sub>CM</sub>	-2	A
Continuous Base Current	I <sub>B</sub>	-100	mA
Peak Pulse Base Current	I <sub>BM</sub>	-200	mA

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P <sub>D</sub>	2	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	62	°C/W
Thermal Resistance, Junction to Leads (Note 6)		$R_{ heta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

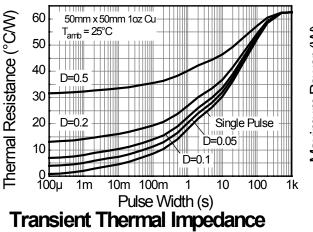
Notes:

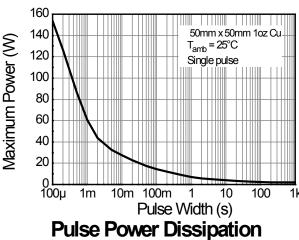
 <sup>5.</sup> For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 6. Thermal resistance from junction to solder-point (at the end of the collector lead).

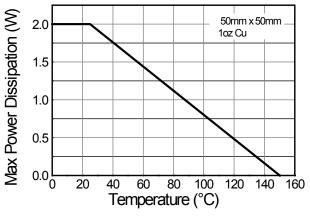
<sup>7.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**







**Derating Curve** 

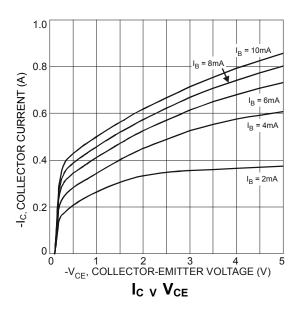


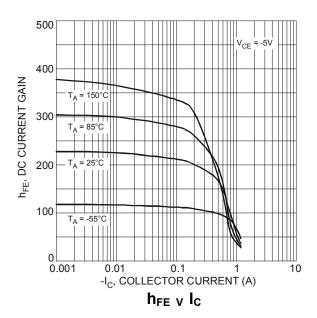
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-100	1	1	٧	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	$BV_{CEO}$	-80	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	_	_	V	I <sub>E</sub> = -100μA
Collector Cut-off Current	I <sub>CBO</sub>	_	_	-0.1 -20	μΑ	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>A</sub> = +150°C
Emitter Cut-off Current	I <sub>EBO</sub>	_	_	-20	nA	V <sub>EB</sub> = -4V
DC Current Gain (Note 8)	h <sub>FE</sub>	25 100 25		_ 250 _	_	$I_C$ = -5mA, $V_{CE}$ = -2V $I_C$ = -150mA, $V_{CE}$ = -2V $I_C$ = -500mA, $V_{CE}$ = -2V
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	_	_	-0.5	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>	_	_	-1.0	V	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
Transition Frequency	f⊤	150			MHz	$I_C = -50$ mA, $V_{CE} = -10$ V f = 100MHz
Output Capacitance	Cobo	_	_	25	pF	V <sub>CB</sub> = -10V, f = 1MHz

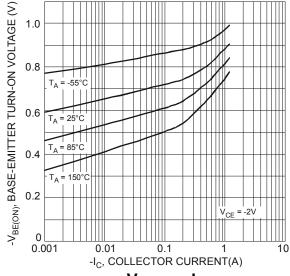
Note:

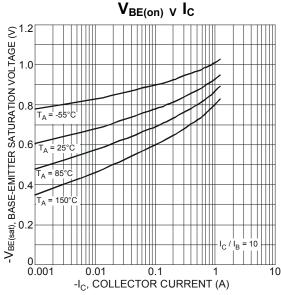
8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

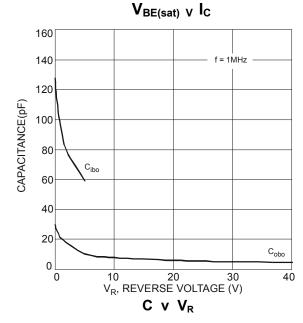


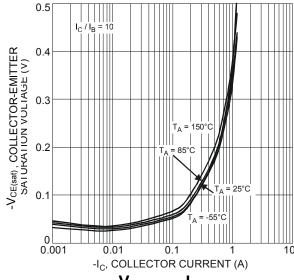


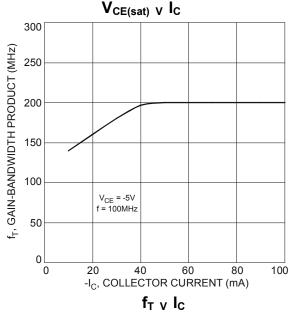










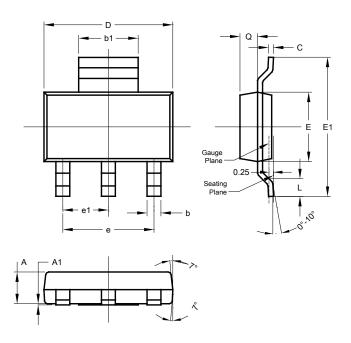




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT223**

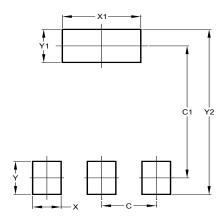


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT223**



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
X	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8 00		



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